



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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Description

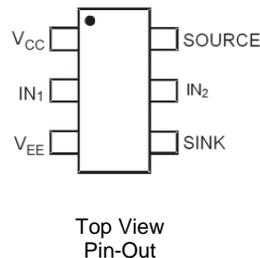
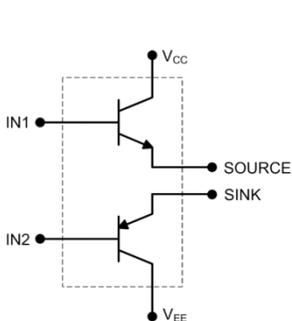
The NK-ZXGD3003E6Q is a high-speed, non-inverting single gate driver designed for switching MOSFETs or IGBTs. It can transfer up to 5A peak source/source current into the gate for effective charging and discharging of the capacitive gate load.

This gate driver ensures rapid switching of the MOSFET to minimize power losses and distortion in high current switching applications. It can typically drive 1.5A into the low gate impedance with just 10mA input from a controller. The turn-on and turn-off switching behaviour of the MOSFET can be individually tailored to suit an application. By defining the switching characteristics appropriately, EMI and cross conduction can be reduced.

Applications

Gate Driving Power MOSFET and IGBTs in:

- AC-DC Power Supplies (SMPS)
- DC-DC Converters
- DC-AC Inverters (i.e. Solar)
- 1, 2 and 3-Phase Motor Control Circuits
- Amplifier Output Stages



Pin Name	Pin Function
V _{CC}	Supply Voltage High
IN ₁ & IN ₂	Driver Input *
V _{EE}	Supply Voltage Low
SOURCE	Source Current Output **
SINK	Sink Current Output **

* Typically connect IN₁ & IN₂ together
 ** Typically connect SOURCE & SINK together

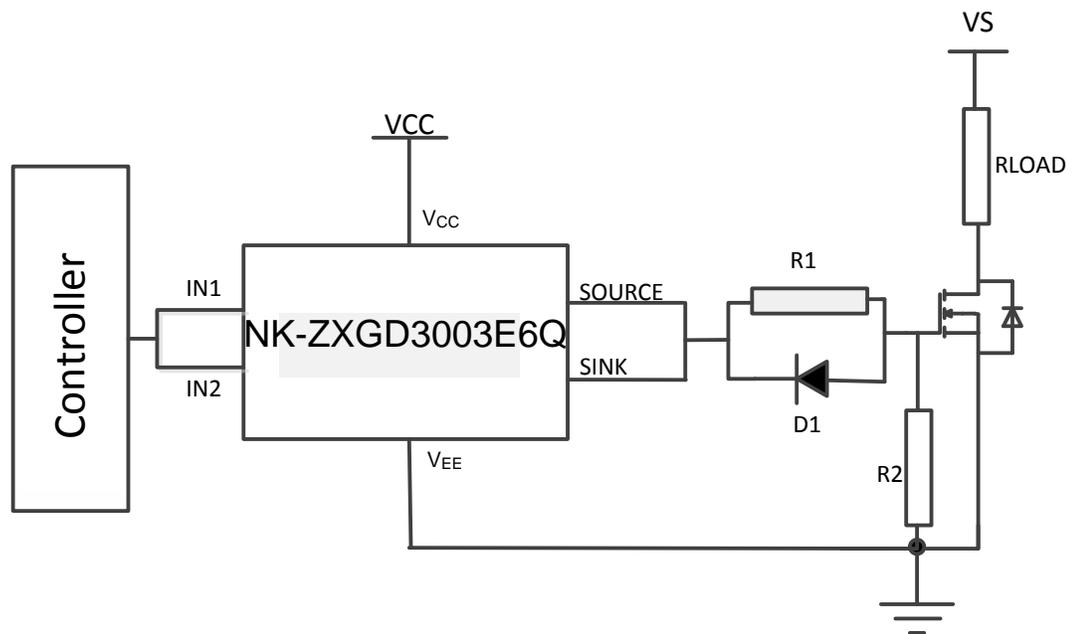
Features

- High-Gain Buffer with Typically 1.5A Output from 10mA Input
- 5 Amps Peak Output Current
- 40V Supply for +20V to -18V Gate Driving to Prevent dV/dt Induced False Triggering and Minimize On-Losses
- Emitter-Follower that is Rugged to Latch-Up/Shoot-Through
- Fast Switching Emitter-Follower Configuration:
 - 2ns Propagation Delay Time
 - 9ns Rise/Fall Time, 1000pF Load
- Optimized Pin-Out to Simplify PCB Layout and Reduce Parasitic Trace Inductances
- Near-Zero Quiescent Supply Current

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.018 grams (Approximate)

Typical Application Circuit



R1, D1 combination can be used for variable turn on and turn off times.

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage, with Respect to V _{EE}	V _{CC}	40	V
Input Voltage, with Respect to V _{EE}	V _{IN}	40	V
Output Difference Voltage (Source - Sink)	ΔV _(source-sink)	±7	V
Peak Pulsed Output Current (Source - Sink)	I _{OM}	±5	A
Peak Pulsed Input Current	I _{IN1} , I _{IN2}	±1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 5 & 6)	P _D	1.1	W
Linear Derating Factor		8.8	mW/°C
Thermal Resistance, Junction to Ambient (Notes 5 & 6)	R _{θJA}	113	°C/W
Thermal Resistance, Junction to Lead (Note 7)	R _{θJL}	105	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

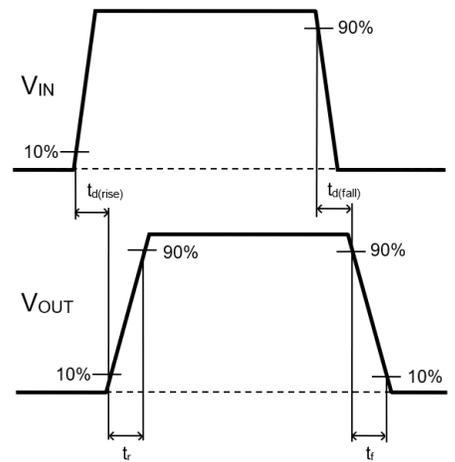
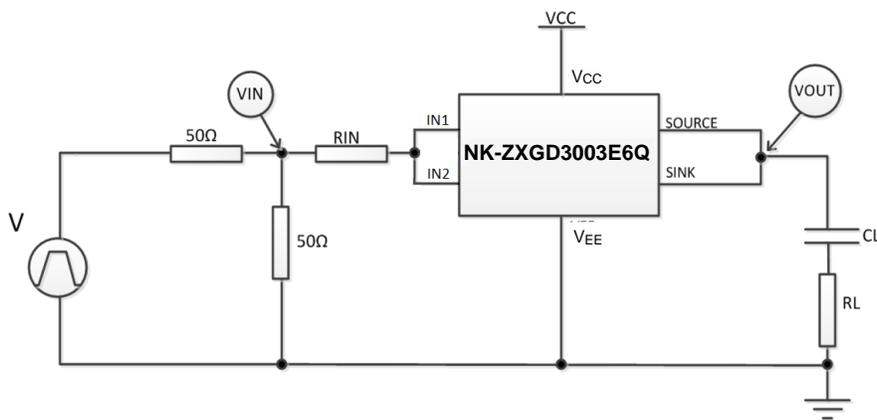
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C
Electrostatic Discharge – Charged Device Model	ESD CDM	1,000	V	IV

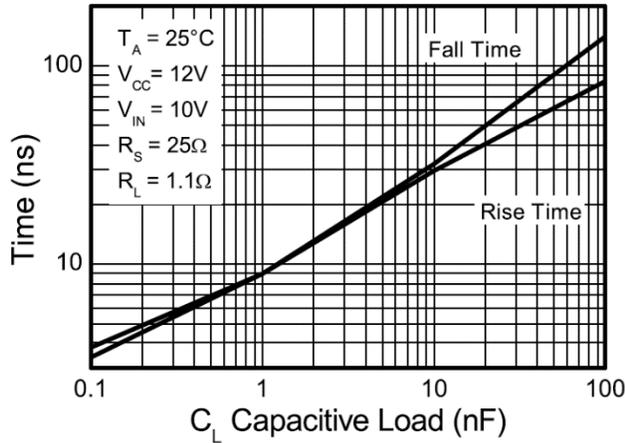
- Notes:
5. For a device mounted on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. The heatsink is split in half with the pin 1 (V_{CC}) and pin 3 (V_{EE}) connected separately to each half.
 6. For device with two active die running at equal power.
 7. Thermal resistance from junction to solder-point at the end of each lead on pin 1 (V_{CC}) and pin 3 (V_{EE}).
 8. Refer to JEDEC specification JESD22-A114, JESD22-A115 and JESD22-C101.

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

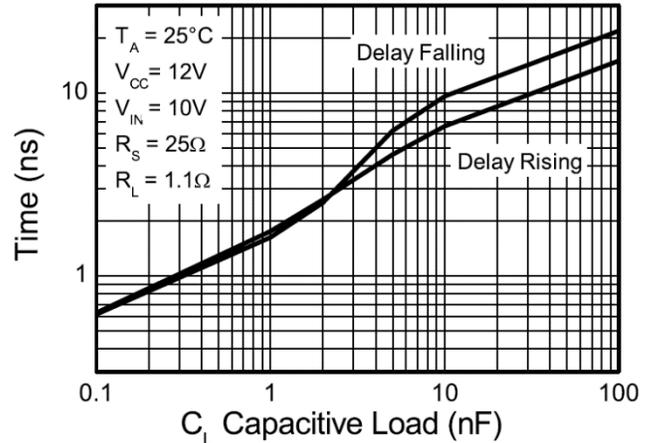
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Output Voltage, High	$V_{OUT(hi)}$	—	$V_{IN1} - 0.4$	—	V	$I_{source} = 1\mu\text{A}$
Output Voltage, Low	$V_{OUT(low)}$	—	$V_{IN1} + 0.4$	—		$I_{sink} = 1\mu\text{A}$
Source Output Leakage Current	$I_{L(source)}$	—	—	1	μA	$V_{CC} = 40\text{V}$, $V_{IN1} = V_{IN2} = 0\text{V}$
Sink Output Leakage Current	$I_{L(sink)}$	—	—	1	μA	$V_{CC} = 40\text{V}$, $V_{IN1} = V_{IN2} = V_{CC}$
Quiescent Supply Current	I_Q	—	—	20	nA	$V_{CC} = 32\text{V}$, $V_{IN1} = V_{IN2} = 0\text{V}$
Peak Pulsed Source Output Current	$I_{(source)M}$	1	1.6	—	A	$I_{IN1} + I_{IN2} = 10\text{mA}$
Peak Pulsed Sink Output Current	$I_{(sink)M}$	1	1.4	—	A	$I_{IN1} + I_{IN2} = -10\text{mA}$
Peak Pulsed Source Output Current	$I_{(source)M}$	—	5	—	A	$I_{IN1} + I_{IN2} = 500\text{mA}$
Peak Pulsed Sink Output Current	$I_{(sink)M}$	—	5	—	A	$I_{IN1} + I_{IN2} = -500\text{mA}$
Gate Driver Switching Times	$t_d(\text{rise})$	—	1.8	—	ns	$V_{CC} = 12\text{V}$, $V_{EE} = 0\text{V}$, $V_{IN} = 0$ to 10V , $C_L = 1\text{nF}$, $R_L = 1\Omega$, $R_{IN} = 25\Omega$
	t_r		8.9			
	$t_d(\text{fall})$		1.7			
	t_f		8.9			
Gate Driver Switching Times	$t_d(\text{rise})$	—	4	—	ns	$V_{CC} = 12\text{V}$, $V_{EE} = 0\text{V}$, $V_{IN} = 0$ to 10V , $C_L = 1\text{nF}$, $R_L = 1\Omega$, $R_{IN} = 1\text{k}\Omega$
	t_r		77			
	$t_d(\text{fall})$		4			
	t_f		85			

Switching Test Circuit and Timing Diagram


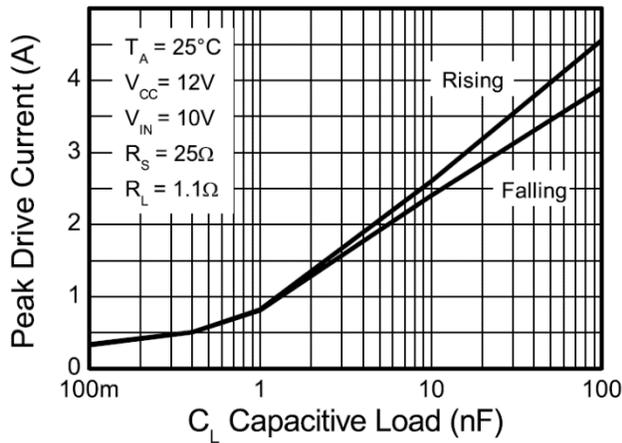
Typical Gate Driver Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



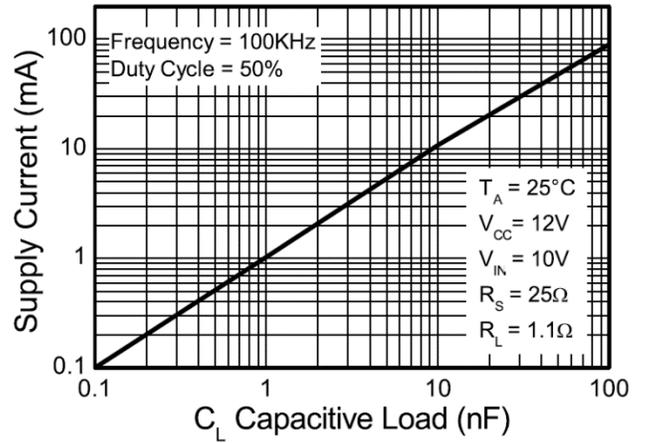
Rise and Fall Time



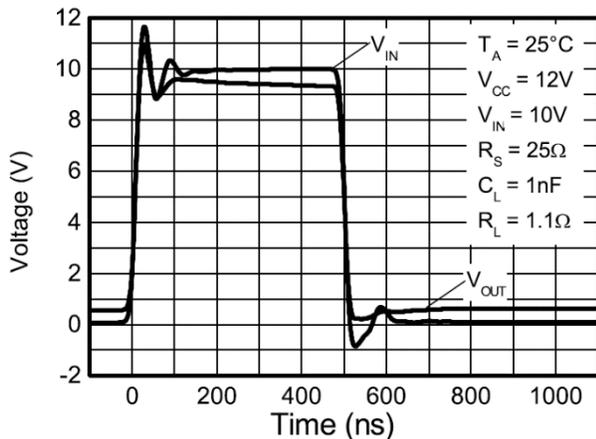
Propagation Delay



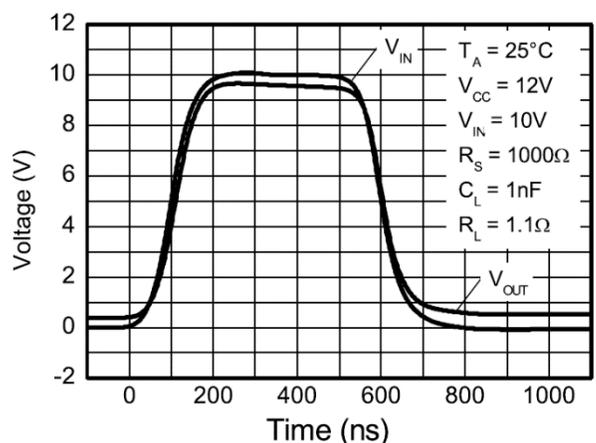
Peak Drive Current



Supply Current

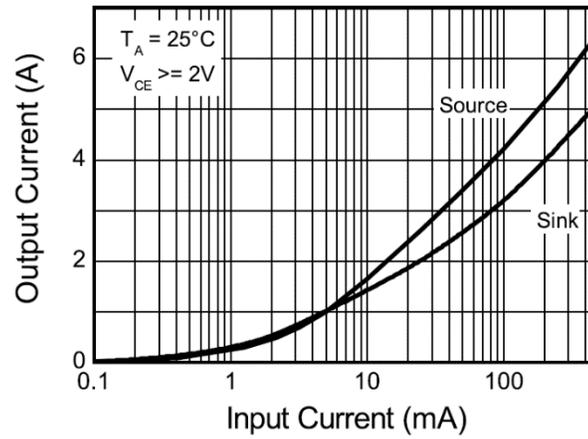


Switching Speed



Switching Speed

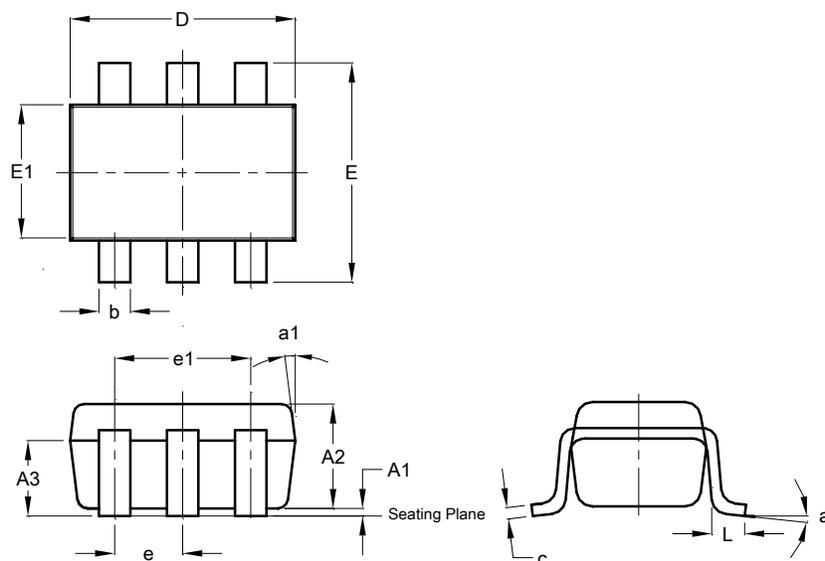
Typical Gate Driver Characteristics (continued)



Output Current vs Input Current

Package Outline Dimensions

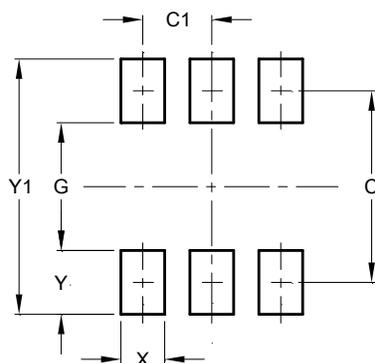
SOT26



SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

Suggested Pad Layout

SOT26



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20